

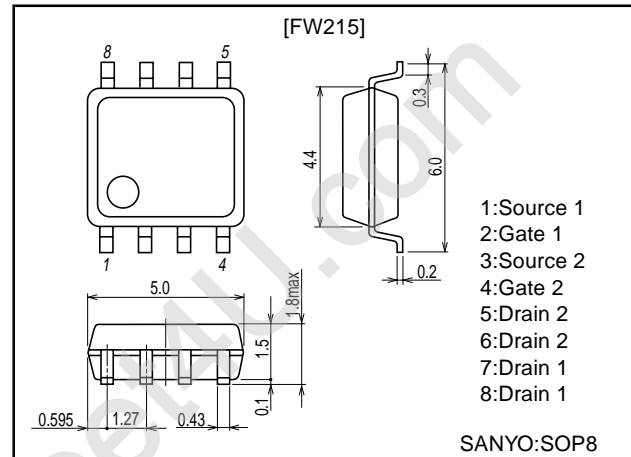
**SANYO****DC-DC Converter Applications****Features**

- Low ON resistance.
- 4V drive.

**Package Dimensions**

unit:mm

2129

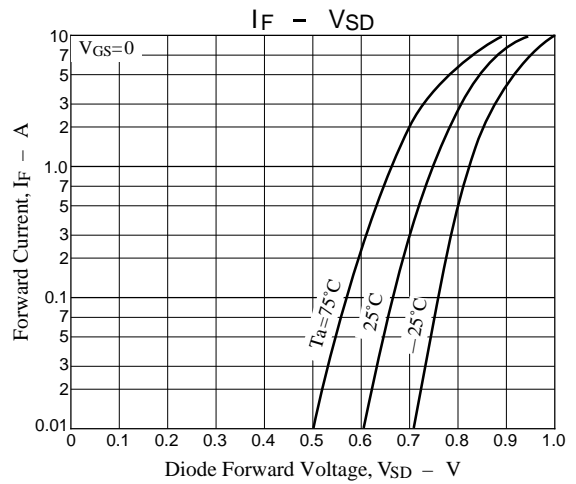
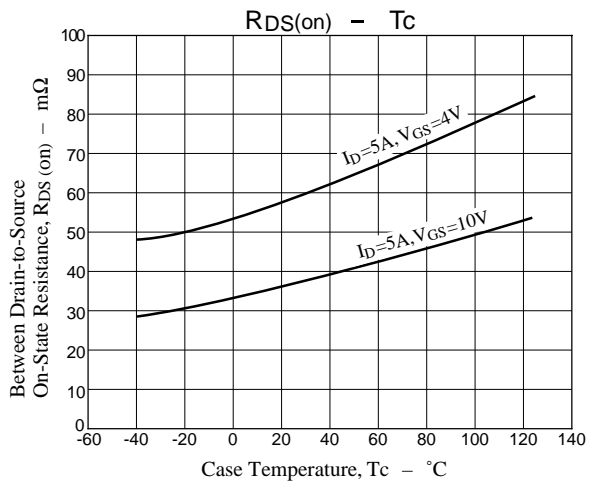
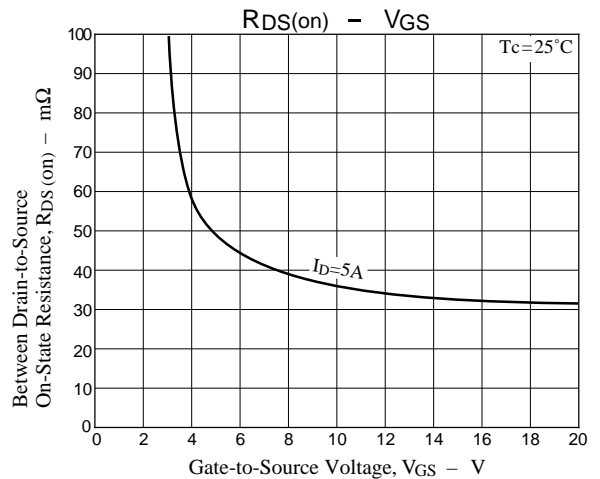
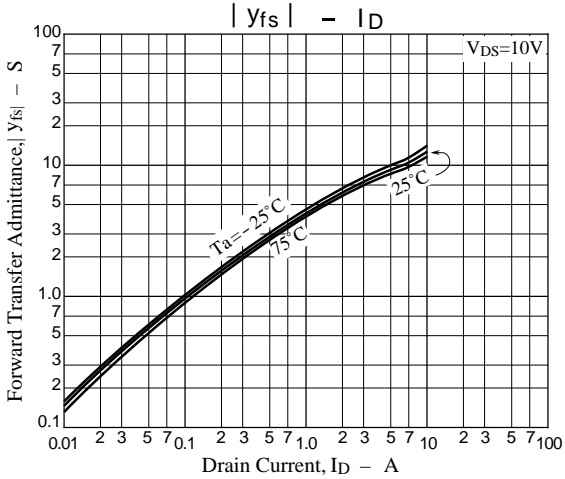
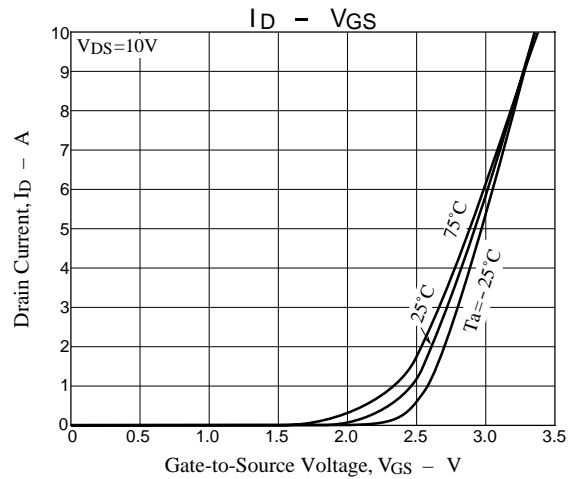
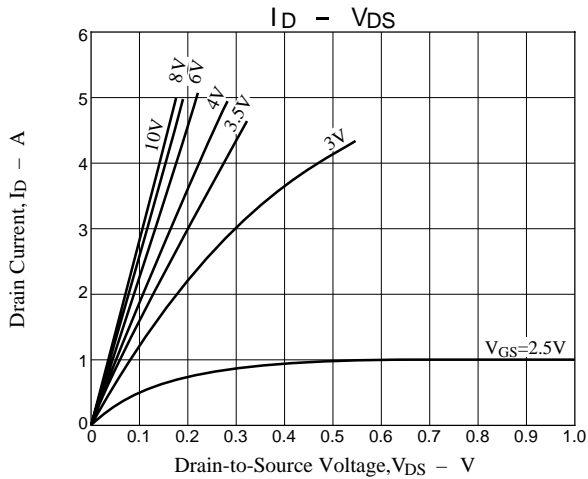
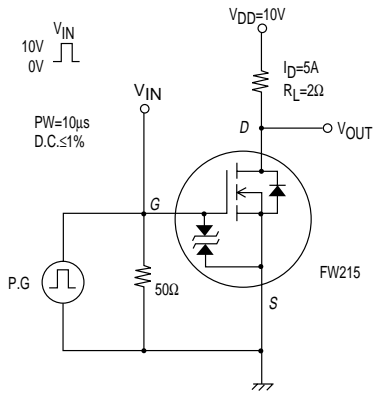
**Specifications****Absolute Maximum Ratings** at Ta = 25°C

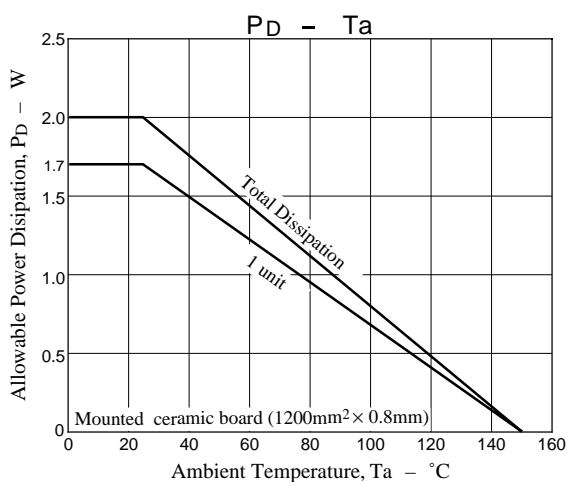
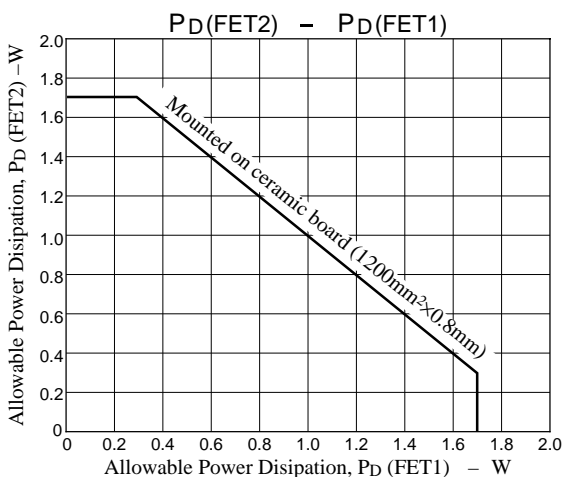
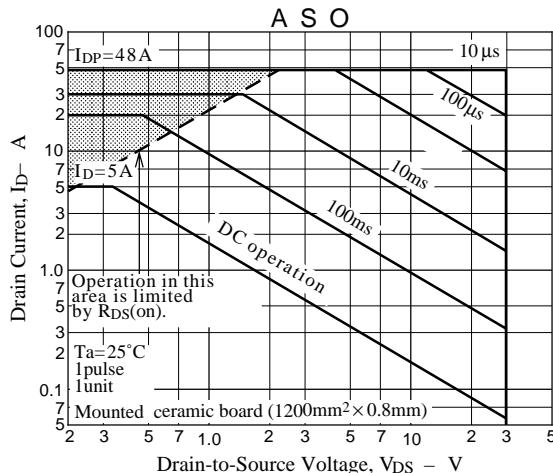
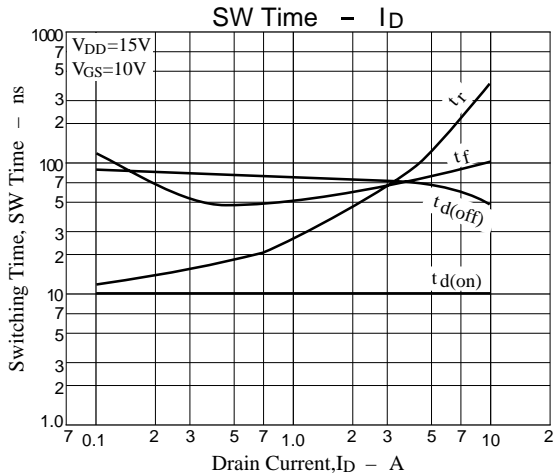
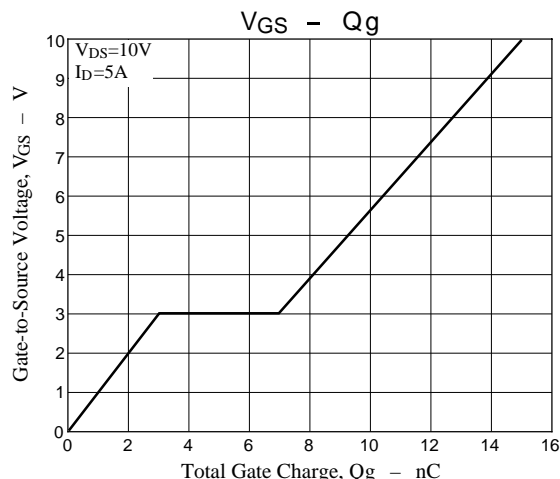
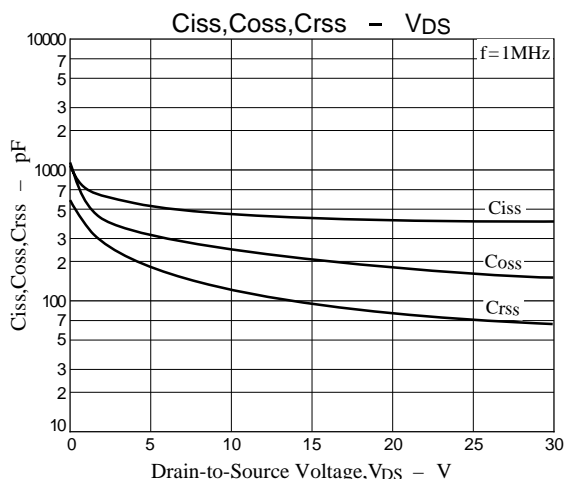
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		30	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 20$	V
Drain Current (DC)	$I_D$		5	A
Drain Current (pulse)	$I_{DP}$	$PW \leq 10\mu s$ , duty cycle $\leq 1\%$	48	A
Allowable Power Dissipation	$P_D$	Mounted on a ceramic board (1200mm <sup>2</sup> ×0.8mm) 1unit	1.7	W
Total Dissipation	$P_T$	Mounted on a ceramic board (1200mm <sup>2</sup> ×0.8mm)	2.0	W
Channel Temperature	$T_{ch}$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

**Electrical Characteristics** at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA$ , $V_{GS}=0$	30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=30V$ , $V_{GS}=0$			100	$\mu A$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 16V$ , $V_{DS}=0$			$\pm 10$	$\mu A$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V$ , $I_D=1mA$	1.0		2.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V$ , $I_D=5A$	5		9	S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)1}$	$I_D=5A$ , $V_{GS}=10V$		36	46	m $\Omega$
	$R_{DS(on)2}$	$I_D=5A$ , $V_{GS}=4V$		58	78	m $\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=10V$ , $f=1MHz$		460		pF
Output Capacitance	$C_{oss}$	$V_{DS}=10V$ , $f=1MHz$		250		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=10V$ , $f=1MHz$		120		pF
Turn-ON Delay Time	$t_{d(on)}$	See Specified Test Circuit		10		ns
Rise Time	$t_r$	See Specified Test Circuit		120		ns
Turn-OFF Delay Time	$t_{d(off)}$	See Specified Test Circuit		70		ns
Fall Time	$t_f$	See Specified Test Circuit		80		ns
Total Gate Charge	$Q_g$	$V_{DS}=10V$ , $V_{GS}=10V$ , $I_D=5A$		15		nC
Gate-to-Source Charge	$Q_{gs}$			3		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$			4		nC
Diode Forward Voltage	$V_{SD}$		$I_S=5A$ , $V_{GS}=0$	1.0	1.2	

Switching Time Test Circuit





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